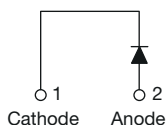


## High Voltage, Input Rectifier Diode, 20 A



2L TO-220 FullPAK



### FEATURES

- Very low forward voltage drop
- 150 °C max. operating junction temperature
- Glass passivated pellet chip junction
- Designed and qualified according to JEDEC®-JESD 47
- Fully isolated package ( $V_{INS} = 2500 V_{RMS}$ )
- UL pending
- Material categorization: for definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)



**RoHS**  
COMPLIANT  
HALOGEN  
**FREE**

### PRIMARY CHARACTERISTICS

$I_{F(AV)}$	20 A
$V_R$	800 V, 1200 V
$V_F$ at $I_F$	1.1 V
$I_{FSM}$	300 A
$T_J$ max.	150 °C
Package	2L TO-220 FullPAK
Circuit configuration	Single

### APPLICATIONS

- Input rectification
- Vishay Semiconductors switches and output rectifiers which are available in identical package outlines

### DESCRIPTION

High voltage rectifiers optimized for very low forward voltage drop with moderate leakage.

These devices are intended for use in main rectification (single or three phase bridge).

### OUTPUT CURRENT IN TYPICAL APPLICATIONS

APPLICATIONS	SINGLE-PHASE BRIDGE	THREE-PHASE BRIDGE	UNITS
Capacitive input filter $T_A = 55$ °C, $T_J = 125$ °C common heatsink of 1 °C/W	18	22	A

### MAJOR RATINGS AND CHARACTERISTICS

SYMBOL	CHARACTERISTICS	VALUES	UNITS
$I_{F(AV)}$	Sinusoidal waveform	20	A
$V_{RRM}$	Range	800, 1200	V
$I_{FSM}$		300	A
$V_F$	10 A, $T_J = 25$ °C	1.0	V
$T_J$		-40 to +150	°C

### VOLTAGE RATINGS

PART NUMBER	$V_{RRM}$ , MAXIMUM PEAK REVERSE VOLTAGE V	$V_{RSM}$ , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	$I_{RRM}$ AT 150 °C mA
VS-20ETS08FP-M3	800	900	1
VS-20ETS12FP-M3	1200	1300	

**ABSOLUTE MAXIMUM RATINGS**

PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum average forward current	$I_{F(AV)}$	$T_C = 51\text{ }^{\circ}\text{C}$ , 180° conduction half sine wave	20	A
Maximum peak one cycle non-repetitive surge current	$I_{FSM}$	10 ms sine pulse, rated $V_{RRM}$ applied	250	
		10 ms sine pulse, no voltage reapplied	300	
Maximum $I^2t$ for fusing	$I^2t$	10 ms sine pulse, rated $V_{RRM}$ applied	316	$\text{A}^2\text{s}$
		10 ms sine pulse, no voltage reapplied	442	
Maximum $I^2\sqrt{t}$ for fusing	$I^2\sqrt{t}$	$t = 0.1\text{ ms to }10\text{ ms}$ , no voltage reapplied	4420	$\text{A}^2\sqrt{\text{s}}$

**ELECTRICAL SPECIFICATIONS**

PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum forward voltage drop	$V_{FM}$	20 A, $T_J = 25\text{ }^{\circ}\text{C}$	1.1	V
Forward slope resistance	$r_t$	$T_J = 150\text{ }^{\circ}\text{C}$	10.4	$\text{m}\Omega$
Threshold voltage	$V_{F(TH)}$		0.85	V
Maximum reverse leakage current	$I_{RM}$	$T_J = 25\text{ }^{\circ}\text{C}$	0.1	mA
		$T_J = 150\text{ }^{\circ}\text{C}$	1.0	

**THERMAL - MECHANICAL SPECIFICATIONS**

PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range	$T_J, T_{Stg}$		-40 to +150	$^{\circ}\text{C}$
Maximum thermal resistance, junction to case	$R_{thJC}$	DC operation	2.8	$^{\circ}\text{C/W}$
Maximum thermal resistance, junction to ambient	$R_{thJA}$		62	
Typical thermal resistance, case to heatsink	$R_{thCS}$	Mounting surface, smooth, and greased	0.5	
Approximate weight			2	g
			0.07	oz.
Mounting torque	minimum		6.0 (5.0)	$\text{kgf} \cdot \text{cm}$ ( $\text{lbf} \cdot \text{in}$ )
	maximum		12 (10)	
Marking device		Case style 2L TO-220 FullPAK	20ETS08FP	
			20ETS12FP	

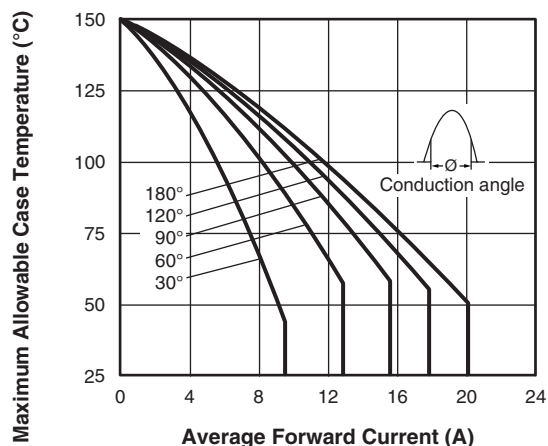


Fig. 1 - Current Rating Characteristics

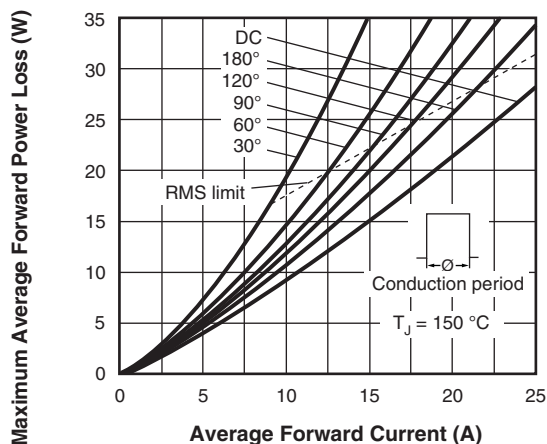


Fig. 4 - Forward Power Loss Characteristics

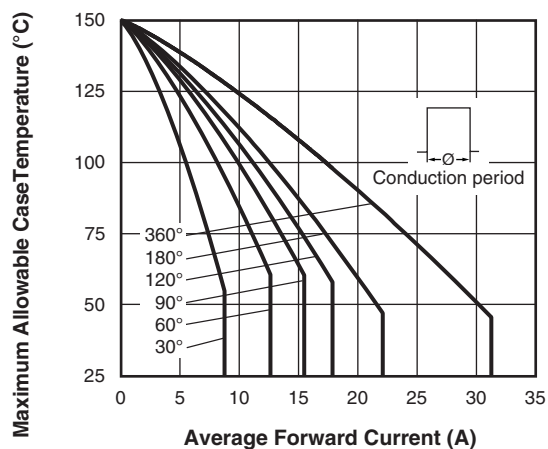


Fig. 2 - Current Rating Characteristics

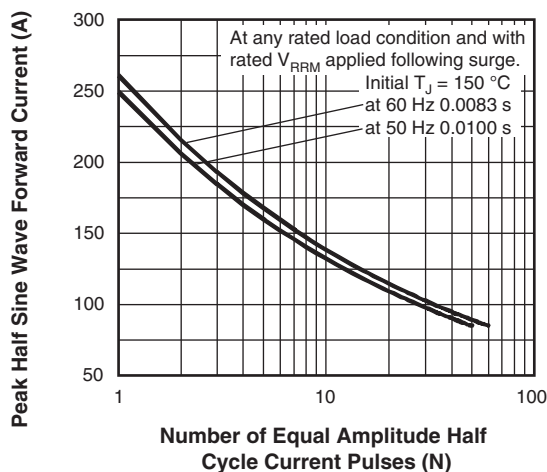


Fig. 5 - Maximum Non-Repetitive Surge Current

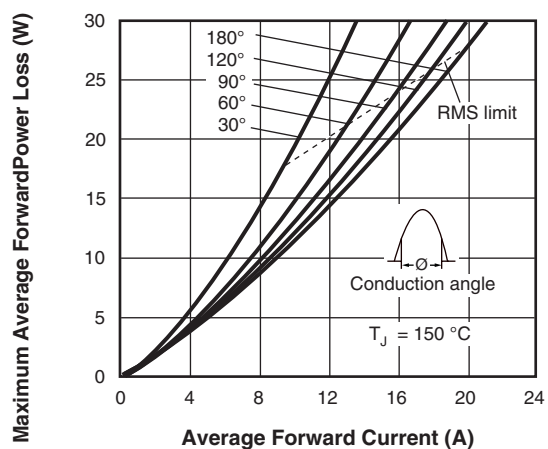


Fig. 3 - Forward Power Loss Characteristics

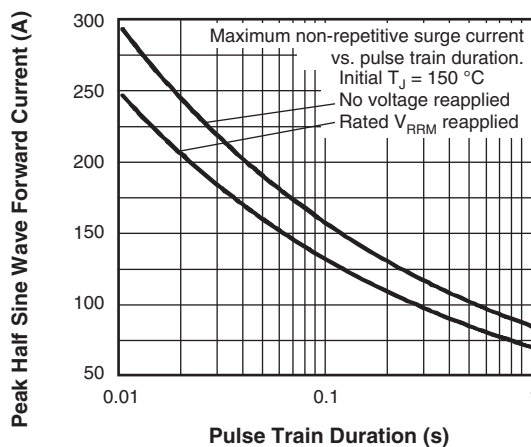


Fig. 6 - Maximum Non-Repetitive Surge Current

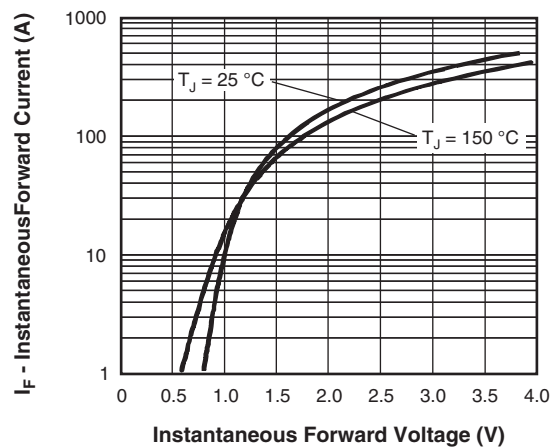
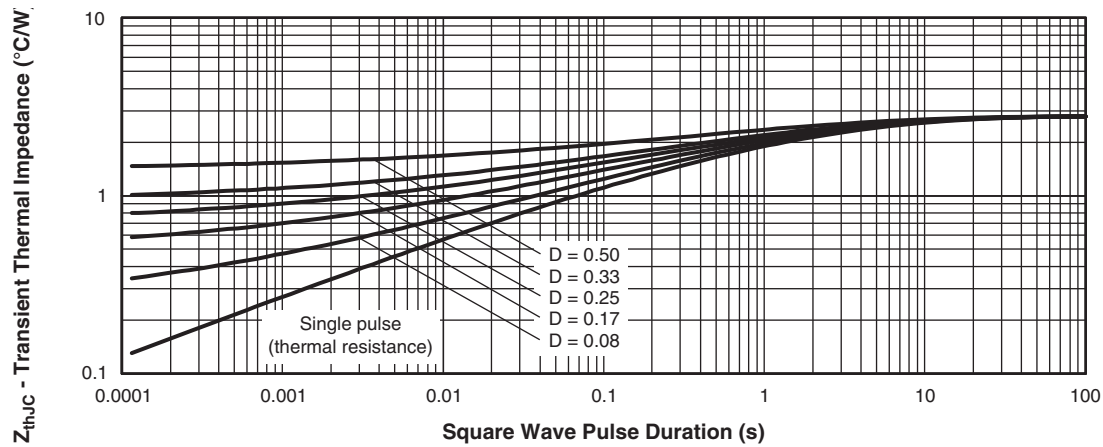


Fig. 7 - Forward Voltage Drop Characteristics


Fig. 8 - Thermal Impedance  $Z_{thJC}$  Characteristics

**ORDERING INFORMATION TABLE**

Device code	VS-	20	E	T	S	12	FP	-M3
	1	2	3	4	5	6	7	8
1	- Vishay Semiconductors product							
2	- Current rating (20 = 20 A)							
	- Circuit configuration:							
3	E = single diode							
	- Package:							
4	T = TO-220							
	- Type of silicon:							
5	S = standard recovery rectifier							
6	- Voltage ratings							
7	- FullPAK							
8	- Environmental digit:							
								08 = 800 V 12 = 1200 V
-M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free								

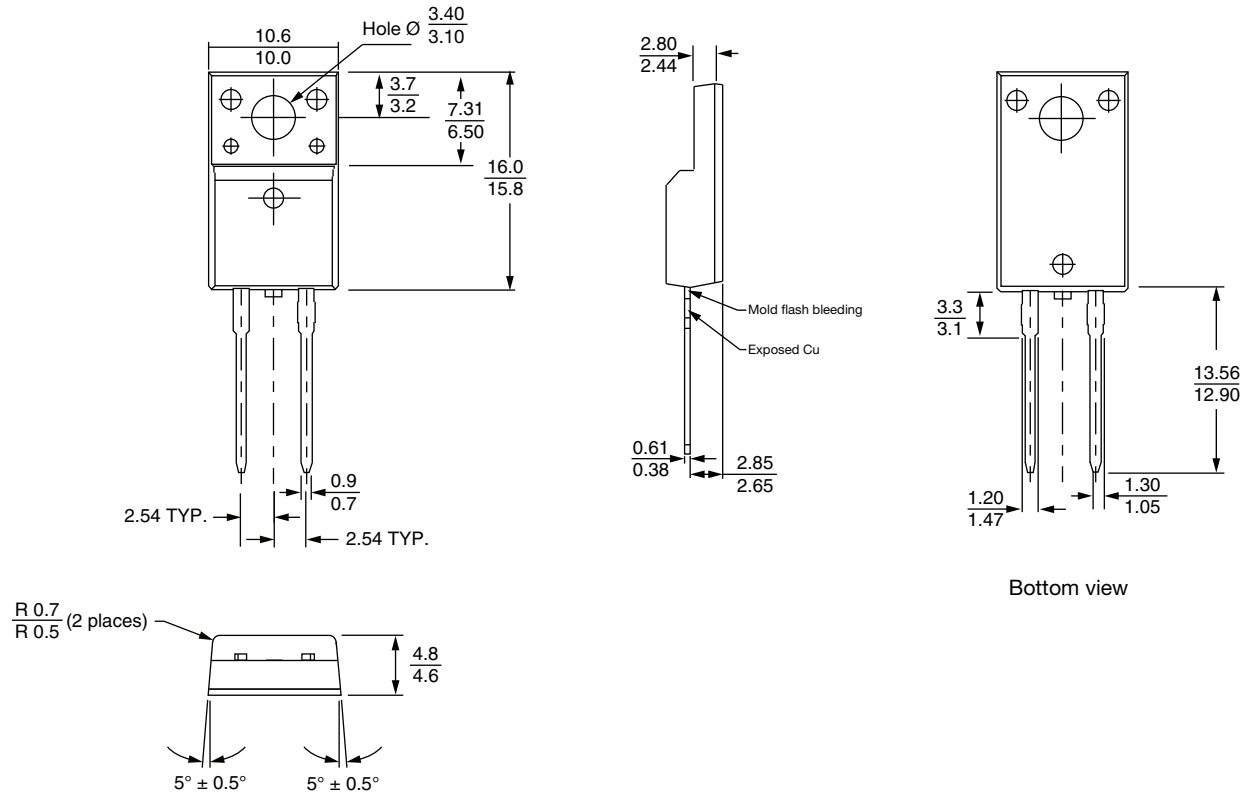
ORDERING INFORMATION (Example)			
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION
VS-20ETS08FP-M3	50	1000	Antistatic plastic tubes
VS-20ETS12FP-M3	50	1000	Antistatic plastic tubes

LINKS TO RELATED DOCUMENTS	
Dimensions	<a href="http://www.vishay.com/doc?96157">www.vishay.com/doc?96157</a>
Part marking information	<a href="http://www.vishay.com/doc?95392">www.vishay.com/doc?95392</a>



## 2L TO-220 FullPAK

**DIMENSIONS** in millimeters





## Disclaimer

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